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OPEN On oscillatory microstructure during cellular growth of directionally solidified Sn-36at.%Ni peritectic alloy

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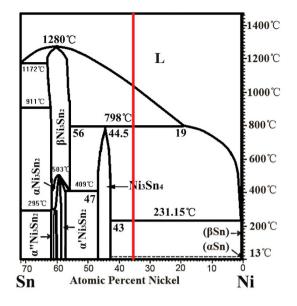
An oscillatory microstructure has been observed during deep-cellular growth of directionally solidified Sn-36at.%Ni hyperperitectic alloy containing intermetallic compounds with narrow solubility range. This oscillatory microstructure with a dimension of tens of micrometers has been observed for the first time. The morphology of this wave-like oscillatory structure is similar to secondary dendrite arms, and can be observed only in some local positions of the sample. Through analysis such as successive sectioning of the sample, it can be concluded that this oscillatory microstructure is caused by oscillatory convection of the mushy zone during solidification. And the influence of convection on this oscillatory microstructure was characterized through comparison between experimental and calculations results on the wavelength. Besides, the change in morphology of this oscillatory microstructure has been proved to be caused by peritectic transformation during solidification. Furthermore, the melt concentration increases continuously during solidification of intermetallic compounds with narrow solubility range, which helps formation of this oscillatory microstructure.

An important class of industrial alloys has been represented in peritectic systems, including Fe-Ni, Cu-Zn, Cu-Sn and Ti-Al which are the most widely known¹⁻³. Solidification microstructures that form under steady state growth conditions have been reasonably well understood during peritectic solidification. However, under non-steady state growth conditions, the peritectic microstructures is also influenced by many other factors like Gibbs-Thomson effect⁴, and temperature gradient zone melting (TGZM) effect^{5,6} etc. Besides, the selection of microstructures in peritectic systems is mostly governed by the coupling effects like convection, nucleation undercooling etc.7,8.

Due to the above reasons, a wide variety of non-steady state microstructures have been revealed in directional solidification in both the hypoperitectic and hyperperitectic regions of peritectic systems⁸⁻¹⁴. Among them, the so-called *banded*⁹ structures and the *oscillatory* structures^{10,12} have been observed in several peritectic systems, including Sn-Cd, Pb-Bi, Fe-Ni alloys^{1,3-11}. The former is featured by bands of both the primary and peritectic phases which form alternately normal to the growth direction⁹. And their formations have been attributed to nucleation followed by the growth of one phase (α or β) ahead of a growing planar front of the other phase (β or α). Besides, this *banded* structure is often related to the *oscillatory* structures^{10,12}. In highly convective hyperperitectic alloys, tree-like structures which appeared as alternate bands and islands in longitudinal cross-sections have been revealed to be continuous structures in Pb-Bi and Sn-Cd alloys^{13,14}. The oscillatory structures are, in fact, a continuous treelike morphology of the primary phase which is surrounded by the peritectic phase¹². And these structures result from an oscillatory movement of the triple junction due to convection in the melt.

The formation mechanisms of both the *banded* and *oscillatory* structures have been extensively analyzed⁸⁻¹⁶. For the former structure, based on the diffusive model⁹ by Trivedi, the peritectic β phase tends to grow simultaneously in the lateral direction which is normal to the growth of α phase and in the thermal gradient direction in directionally solidified peritectic systems. Thus, the banding cycle which is controlled by the growth competition between the β nuclei and the preexisting α phase under non-steady-state conditions can be observed. The spreading of the peritectic phase on the preexisting primary phase following nucleation was also predicted by

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phase-field modeling by Lo *et al.*¹³. For the *oscillatory* structure, Park and Trivedi^{8,12} have shown that this treelike structure could only be observed in a tube with larger diameter, and disappeared when the diameter of the tube is 0.6 mm or less, suggesting that melt convection has obvious influence on this structure. The model by Karma *et al.*¹⁵ yields an oscillatory structure which is formed through continuous growth of both phases instead of nucleation at the boundary of the pre-existing phase. Mazumder *et al.*¹⁰ have further confirmed that oscillating melt convection could lead to an oscillatory, treelike structure. Liu and Trivedi¹⁶ presented that a large treelike primary phase could be produced by strong oscillatory convection while the banding cycle was independent of it. Thus, the melt concentration should be critical in determining the growth morphology of structures during peritectic solidification^{17–23}.

In the previous analyses discussed above, these non-steady state structures like *banded* and *oscillatory* structures have been confirmed to be significantly influenced by either nucleation competition between α/β phases phase or thermosolutal convection in the melt. However, all of these structures are observed in peritectic systems where both the primary α phase and peritectic β phase are solid solution phases. None of these oscillatory structures have been found in peritectic systems containing intermetallic compounds except that by Kohler *et al.*³. For peritectic systems containing intermetallic compounds, as no steady-state solute redistribution of melt can be achieved²⁴, some interesting microstructures which are distinct from that of solid solution phase can be obtained²⁴⁻²⁶. In addition, the dimensions of both the *banded* and *band-like* microstructure which only exists at few positions of the sample. But in our recent experiment, an *oscillatory* microstructure which only exists at few positions of the sample has been observed in directionally solidified Sn–Ni hyperperitectic alloy. The size of this microstructure is much smaller as compared with previous results⁸⁻¹⁶. In a word, this microstructure which is found in peritectic system containing intermetallic compound is distinct from that in peritectic system containing intermetallic compound is distinct from that in peritectic system containing intermetallic compound is distinct from that in peritectic system containing solid solution phases. And this might be attributed to the difference in solute redistribution between intermetallic compounds and solid solution phases.

In this paper we shall present a new kind of *oscillatory* microstructure which has been observed in Sn–Ni peritectic alloy in which both the primary Ni_3Sn_2 phase and peritectic Ni_3Sn_4 phase are intermetallic compounds with narrow solubility range. Although *banded* or *oscillatory* structure can also be observed at high growth rate^{27,28}, the growth rate in the present work is rather small. For these *banded* structures^{27,28} are formed due to the growth oscillation between planar and cell growth²⁹. The aim of this article is threefold: (1) to characterize this *oscillatory* microstructure and analyze how this microstructure is formed; (2) to analyze the influence of convection on formation of this oscillatory microstructure through analyzing the characteristic scale of this structure; (3) to discuss whether the solute redistribution of intermetallic compounds during solidification can influence the morphology of this microstructure.

Results

Figure 1 shows that under equilibrium solidification³⁰, Sn–36at.%Ni alloy²² begins at $T_L = 1040$ °C with a primary precipitation of Ni₃Sn₂ phase: L \rightarrow Ni₃Sn₂, followed by a peritectic reaction at $T_P = 798$ °C: L + L + Ni₃Sn₂ \rightarrow Ni₃Sn₄. BSE (backscattered electron) microstructures of the longitudinal sections of directionally solidified Sn–36.at% Ni alloy are shown in Fig. 2. The growth direction of the sample is presented as the arrow direction which is parallel to the temperature gradient. The dark gray/light gray phases represent the primary Ni₃Sn₂(α)/peritectic Ni₃Sn₄ (β) phases, respectively. The remaining white one represents the eutectic (Ni₃Sn₄ + Sn)^{4.6.7}. By relating to the Sn–Ni phase diagram, primary Ni₃Sn₂ phase precipitates from the liquid exhibiting deep-cellular morphology. With temperature decreases, the peritectic Ni₃Sn₄ phase forms at the primary Ni₃Sn₂/liquid interface at T_P, as illustrated

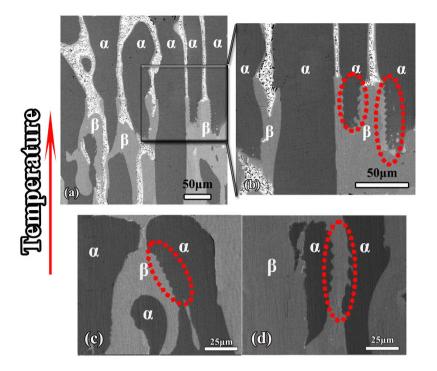


Figure 2. SEM micrographs showing this novel oscillatory microstructure in directionally solidified Sn-36at.%Ni peritectic alloy, and (**b**) is the enlarged view of local position $(\mathbf{a}-\mathbf{d})$ are the views of this novel oscillatory microstructure in the same directionally solidified Sn-36at.%Ni peritectic sample at temperatures lower than those of (\mathbf{a},\mathbf{b}) .

in Fig. 2. It is worth noting that, associated with deep-cellular morphology, an *oscillatory* microstructure with a "wave-like" morphology can only be observed below T_P , which are marked by the dashed lines. The feature of this morphology is that the interface between Ni_3Sn_2/Ni_3Sn_4 phases is curved, quite similar to that of secondary branches during dendritic growth. Here (c) and (d) are the views of this novel oscillatory microstructure in the same sample at temperatures lower than those of (a) and (b).

In this work, this *oscillatory* microstructure might be identified as secondary branches or non-steady state *banded* which results from the nucleation competition between Ni_3Sn_2 and Ni_3Sn_4 phases or continuous *treelike* microstructure¹² which is caused by solutal convection. The following discussion in this section aims to shed light on how this *oscillatory* microstructure is formed. The first conjecture that the this *oscillatory* microstructure might be identified as secondary branches can be eliminated first. Morphologically speaking, there is an obvious resemblance between this *oscillatory* microstructure and dendrite, which has also been discovered in eutectic alloy³¹. However, this resemblance only shows that they have similar shapes. On the one hand, this *oscillatory* microstructure is much smaller as compared with that of secondary dendrite arms. Thus, this *oscillatory* microstructure is closely associated with peritectic solidification, and can not be identified as stretch of secondary dendrite arms.

The assumption that this *oscillatory* microstructure might be caused by nucleation competition between Ni_3Sn_2 and Ni_3Sn_4 phases should also be clarified. If the Ni_3Sn_4 phase grows laterally, the Ni_3Sn_2 phase also advances in the normal direction. This will give rise to a slanted or a curved interface. However, this *oscillatory* microstructure can be observed in only few positions in the sample, indicating that the nucleation competition which occurs in the whole sample can not take place. In addition, if nucleation competition really occurs, then as shown by Gandin *et al.*³², the lateral growth of Ni_3Sn_4 phase slowly initiates, but after a short time the velocity increases rapidly, approximately as the square of the undercooling. However, abrupt change in the curved Ni_3Sn_4 Ni₃Sn₄ interface which is caused by this rapid increase of lateral growth of Ni_3Sn_4 phase can not be observed. Thus, nucleation competition between Ni_3Sn_2 and Ni_3Sn_4 phases can also be eliminated.

Due to the distinct formation mechanism of banded and oscillatory microstructure, it is critical to identify whether this oscillatory-like microstructure in the present work is the *oscillatory* microstructure first. It has been proposed that successive polishing can reveal whether these bands are discrete or interconnected^{8,12}. Thus, as shown in Fig. 3, successive sectioning of the oscillatory microstructure observed in Fig. 2b has been made. Total polishing height of the sample increases from a to c, and the height of every polishing is $20 \,\mu\text{m}$. It can be deduced from the scales in both Figs 2 and 3 that the dimension of this oscillatory structure is rather small, about $5 \sim 8 \,\mu\text{m}$ in average, so the polishing thickness is rather small. Successive sectioning shows that the microstructure does not consist of discrete bands, but is one continuous treelike structure of the peritectic Ni₃Sn₂ phase with periodic branches surrounded by the Ni₃Sn₄ phase. Besides, it has been confirmed by Trivedi and Park⁸ that fluid flow effects are dominant at low growth rate. Thus, the formation of this oscillatory microstructure can be explained

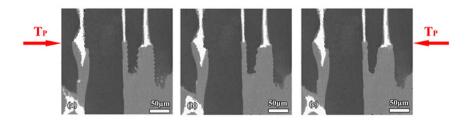


Figure 3. SEM micrographs show the variation of the morphology of this oscillatory after experiencing successive polishing, the polishing depth increases from (a-c).

as follows¹⁰. At the point P where the three phases are in contact and in local equilibrium, solute concentration increases as solidification proceeds. During the solidification of large diameter samples (4 mm) of binary alloys, quasi-periodic convection may set in¹⁰. The temperature and composition field oscillates in a periodic or quasi-periodic manner, and, hence, the composition profile at the interface may have a complex time-dependent behavior. This, in turn, will cause a periodic or quasi-periodic fluctuating motion of P. And a curve that may look like an oscillating layered structure with arms stretching out is delineated.

Discussion

As discussed above, this oscillatory microstructure is formed due to oscillatory melt convection. Thus, before analyzing the morphology of this structure, it is necessary to determine the extent of convection during solidification. Dependence of thermosolutal convection on the diameter of the sample has shown that^{10,15,16} not only the convective transport was greater than diffusive transport, but also the flow was unsteady for tube diameters greater than 3 mm. The flow in the melt for these samples shows periodic or quasi-periodic oscillatory behaviors. Besides, it has been confirmed by Karma *et al.*¹⁵ that the binary alloy system must be highly convective due to the rejection of lighter solute at the interface, which is similar to Sn–Ni peritectic system.

Mazumder *et al.*¹⁰ have proposed that the expression U_C/v_p could be used to describe the extent of thermosolutal convection: diffusion, steady and unsteady convection. Here U_C is the larger one of fluid rate along/normal to the growth direction; v_p is the growth rate of the sample. According to their numerical analysis, in the case of diffusive transport ($U_C/v_p \sim 0$), the predications by the diffusive model⁹ can be reproduced, and a regular *banded* microstructure can be observed. This is not consistent with the oscillatory microstructure in the present work, indicating that the melt convection can not be neglected. In the case of convection transport, steady/unsteady convection is also distinguished when U_C/v_p is 1 ~ 10 or above 100¹⁰.

Although accurate description of the extent of thermosolutal convection can hardly be obtained through the experimental observation, the range of the extent of thermosolutal convection can be reasonably estimated through experimental observations since different microstructures are formed in the case of different extents of thermosolutal convection. The effect of steady convection is mainly to establish the curvature of the primary/peritectic interface, while the oscillatory interface development between primary and peritectic phases is due to unsteady oscillatory convection¹⁰. But according to the prediction by Mazumder et al¹⁰, the fractional area of the respective phases changes with time due to the continuous rejection of solute at the interface and convective-diffusive transport. In the case of steady convection, the fractional area of the primary phase gradually decreases to zero until the interface is completely covered by the peritectic phase. For unsteady oscillatory convection, the fractional area of the primary phase undergoes an oscillatory decay. However, it can be found from Fig. 2 that the oscillatory microstructure in the present work can be formed due to neither steady nor unsteady convection. The decay of the fractional area of the primary phase is not obvious in the present work, and the oscillatory morphology just extends along the curved Ni₃Sn₂/Ni₃Sn₄ interface. According to Mazumder et al.¹⁰, the decrease rate of fractional area of the primary Ni₃Sn₂ phase is about 1.5 times that of the growth velocity. However, the "height" of the wave h is defined as the perpendicular distance from the "weak" to the "trough" of the wave. From the experimental results, the values of h are about $1.8 \sim 2.5 \,\mu\text{m}$, which is obviously larger than that by steady convection (1.5 µm). Furthermore, the change in wavelength of this oscillatory microstructure is not such obvious. All the observations discussed above show that the extent of thermosolutal convection is in the intermediate state of steady and unsteady convection, that is, $10 < U_C / v_P < 100$.

Before analyzing the formation of this oscillatory microstructure, it is critical to accurately characterize this wave-like oscillatory structure. The most distinctive feature of this oscillatory microstructure is its wave-like morphology. Thus, the wavelength of this oscillatory microstructure is measured. As shown in Fig. 4a, besides the measured wavelength of this oscillatory microstructure at different locations of the sample, the temperature ranges in which these microstructures exist are also determined. As a matter of fact, different amounts of waves can be observed at the curved Ni₃Sn₂/Ni₃Sn₄ interface in different deep-cells with oscillatory morphology. The number of wavelength in every oscillatory microstructure is denoted as 1, 2, 3,...N, and the corresponding wavelength measured is λ_1 , λ_2 , λ_3 , ... λ_N . In the present work, the wavelength is measured from the lower temperature to the higher temperature of the oscillatory microstructure. Thus, the temperature of λ_N is higher than that of λ_1 . Oscillatory microstructures having waves less than 4 are neglected for accuracy.

Four features of this oscillatory microstructure can be found from experimental results. The former three ones can be found directly from Fig. 4b. First, the change in wavelength is quite small in the oscillatory microstructure of the same cell. Second, even obvious variation in wavelength of the same cell can not be observed, the wavelengths at lower temperatures are larger than them at higher temperatures in the same cell. Third, in general, the

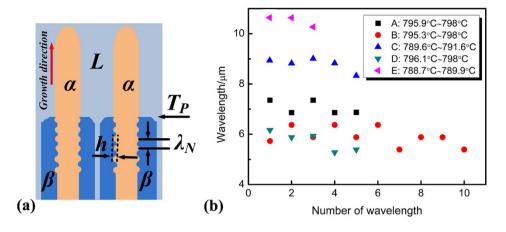


Figure 4. Measurement of the wavelength of this oscillatory microstructure. (a) illustration of measurement of the wavelength, (b) the variation of wavelength measured with temperature.

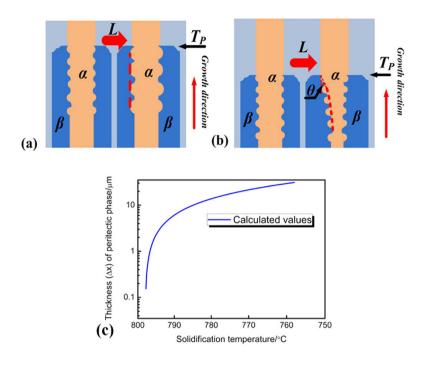
wavelengths at lower temperatures are larger than those at higher temperatures no matter whether they are in the same cell. The last feature which is especially interesting can be found in Fig. 2. That is the curved Ni_3Sn_2/Ni_3Sn_4 interfaces in this oscillatory microstructure gradually move to the center of the cells during solidification. All of these features suggest that the microstructure change takes place during following solidification, indicating the instability of this oscillatory microstructure.

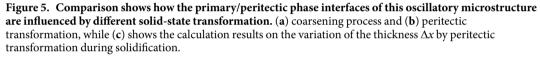
Based on the discussion in this work, the oscillatory microstructure can be influenced by either oscillatory convection or peritectic transformation. Since peritectic transformation can not change the wavelength of the oscillatory microstructure, it is believed that the extent of the oscillatory convection can be identified if there are changes in the wavelength as a function of distance. It has been proposed that¹⁰ in the case of oscillatory thermosolutal convection, the wavelengths of both primary and peritectic phases would change with distance. Consequently, the presence of oscillatory convection can be identified if there are function of distance. Thus, the former three features can be concluded to be caused by convection during solidification, which is distinct from the last feature. Combining with these three features, the effect of convection on this oscillatory microstructure will be analyzed in the Discussion section in detail. In addition, the interesting modification in the curved Ni₃Sn₄/Ni₃Sn₄ interfaces of this oscillatory microstructure will be discussed as follows first.

It can be observed from Fig. 2 that primary Ni_3Sn_2 phase is completely enclosed by peritectic Ni_3Sn_4 phase after peritectic reaction. Thus, only solid state transformation can lead to the movement of the curved Ni_3Sn_2/Ni_3Sn_4 interface of this oscillatory microstructure. During peritectic solidification, the peritectic phase can be formed through three kinds of reactions: peritectic reaction, liquid precipitation and peritectic transformation¹. Both the solid and liquid phases are involved in the former two reactions while peritectic transformation occurs through solute/solvent transport between primary/peritectic phases. Besides peritectic transformation, coarsening process by the Gibbs-Thomson effect may also lead to change in "wavelength" as that in secondary dendrite arms in peritectic alloys^{4–6}.

So, the following explanation is presented to distinguish how the curved interfaces of this oscillatory microstructure move. During the coarsening process in solid phases, the fractional area covered by the respective phases will not change with time. As shown in Fig. 5a, a line which interconnects all the troughs of the waves is depicted. If this change is caused by the Gibbs-Thomson effect, as the Ni₃Sn₂/Ni₃Sn₄ interface keeps still, this line will also keep still. On the contrary, the fractional area covered by the respective phases will change with time if peritectic transformation occurs. Namely, the fractional area by Ni₃Sn₂/Ni₃Sn₄ phase will decrease/increase. As shown in Fig. 5b, a line which connects all the troughs of the waves is also depicted. During peritectic transformation, the Ni₃Sn₂/Ni₃Sn₄ interface moves to the center of the cell, and this line also moves to the center of the cell. As the thickness of peritectic phase by peritectic transformation Δx continues increasing during solidification, the Ni₃Sn₂/Ni₃Sn₄ interface gradually moves to the center of the cell. As a result, an intersection angle θ is formed between the initial and final positions of the interfaces.

The latter view that this change in interface is caused by peritectic transformation is supported by our experimental results. The microstructures in Fig. 2 provide an ideal opportunity to find the evidence. A typical deep-cellular growth of primary Ni₃Sn₂ phase is illustrated, and the amount of waves is large enough to give an accurate conclusion. Figure 2b shows that the Ni₃Sn₂/Ni₃Sn₄ interface gradually moves to the center of the cell, and an intersection angle θ is formed. Since the rate of peritectic transformation is not constant³³, the depicted line shown in Fig. 5b is curved. Thus, the intersection angle θ is not constant, but changes during solidification. As peritectic transformation has been proved to be the reason for the movement of interfaces, the degree of peritectic transformation is estimated. The description of peritectic transformation has been presented by many researches³³⁻³⁵. Here, for the case of simplicity, the analytical presentation by John *et al.*³³ is used:





$$\frac{(\Delta x)^2}{2t} = D_{\beta} \frac{(C_{\beta}^L - C_{\beta}^{\alpha})(C_L^{\beta} - C_{\alpha}^{\beta})}{(C_{\beta} - C_{\alpha}^{\beta})(C_L^{\beta} - C_{\beta})}$$
(1)

where Δx is the thickness of peritectic phase formed through peritectic transformation. The explanations of these concentrations can be found in Ref. 33. D_{β} is the average diffusion coefficient of peritectic β phase, and can be expressed as⁷:

$$D_{\beta} = D_0 \, \exp\left(-\frac{Q}{R_a T}\right) \tag{2}$$

where D_0 is a physical constant depending on the alloy composition, R_a is gas constant, 8.314 J/mol·K., and Q is the activation enthalpy, respectively. In Sn–Ni peritectic system, the physical constant $D_0 = 5 \times 10^{-9} \text{ m}^2/\text{s}$, the activation enthalpy Q = 19150 J/mol is obtained by averaging the values from previous researches^{36,37}.

The calculation result is illustrated in Fig. 5c. As solidification proceeds, the peritectic phase obtained through peritectic transformation increases very quickly from T_P to 788 °C (the lowest temperature at which the oscillatory microstructure is observed). As shown in Fig. 4a, the "height" of the wave *h* is defined as the perpendicular distance from the "weak" to the "trough" of the wave. The values of *h* are influenced by both the oscillatory convection at T_P and following peritectic transformation. Since the values of *h* are about $1.8 \sim 2.5 \,\mu\text{m}$, which is much lager than that by the oscillatory convection at T_P , it therefore can be concluded that the difference in the values of *h* is caused by peritectic transformation which can actually lead to the movement of the Ni₃Sn₂/Ni₃Sn₄ interface.

The driving force for peritectic transformation is the diffusion driven by the compositional difference $C_{\beta}^{L} - C_{\beta}^{\alpha 1}$ across the β phase, causing it to thicken. Here C_{β}^{L} and C_{β}^{α} are the concentrations of peritectic β phase in equilibrium with the liquid and primary α phase, respectively. The solubility range of peritectic Ni₃Sn₄ phase is much smaller as compared with those of solid solution phases in other peritectic systems. Thus, the driving force for peritectic transformation is small in Sn–Ni peritectic alloy. However, the small thickness of peritectic Ni₃Sn₄ phase by peritectic transformation Δx is still large enough to delineate the intersection angle θ . For every trough P_N (N = 1, 2, 3, ... N) at the curved line shown in Fig. 5b, the corresponding wavelength measured is λ_N , and the corresponding thickness by peritectic transformation is Δx_N . As shown in Fig. 6a, PP' is the distance between the peak and of trough of the wave before peritectic transformation. When the number of N is large enough, then, θ_N is very close to θ_{N-1} , and a geometrical relationship can be obtained:

$$\frac{\Delta x_N - \Delta x_{N-1}}{\lambda_N} = \tan \theta_N \tag{3}$$

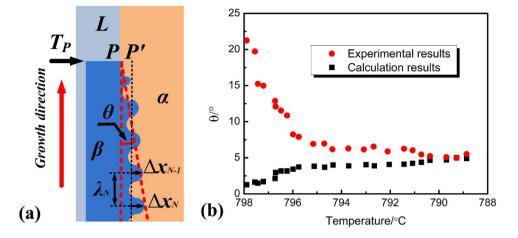


Figure 6. The mechanism how the primary/peritectic phase interface of this oscillatory microstructure move. (a) a geometrical relationship between thickness of peritectic phase by peritectic transformation Δx and λ_N , (b) the comparison between the experimental results and calculation results of the intersection angle θ during solidification.

In order to avoid the negative theta, the measurement on the oscillated interfaces including Fig. 2c and d is not carried out along the growth direction of the sample, instead, it is carried out along the curved Ni_3Sn_2/Ni_3Sn_4 interface.

The experimental results and calculation predictions of the intersection angle θ are shown in Fig. 6b. During calculation, the wavelengths λ_N used are measured in the experiment. It can be found that the calculation results are always smaller as compared with the experimental results. However, this difference decreases during solidification, and the results are very close to each other at the lowest temperatures. The reason why this difference in intersection angle θ occurs maybe found from Equation (3). At temperatures in the vicinity of T_P the peritectic phase formed by peritectic transformation is thin, so the values of θ obtained through Equation (3) is small. However, in fact, the rationality of Equation (3) lies in that N is large enough, so at the initial of peritectic transformation, this difference is really obvious. Generally speaking, our calculation results overestimate the intersection angle θ at every temperature. The most probable reason is that the small thickness of peritectic Ni₃Sn₄ phase by peritectic transformation Δx is overestimated. The models on peritectic transformation presented^{33–35} are based on solid solution phases with constant liquidus and solidus slopes. This is distinct from Sn–Ni peritectic system where both the primary Ni₃Sn₂ and peritectic Ni₃Sn₄ phases are intermetallic compound phases.

In the case of convective flow, the wavelength/band spacing of phases is closely related to the flow in the melt¹⁰, besides, this characteristic scale can be easily measured. Therefore, it is convenient to analyze the effect of convection on this oscillatory microstructure through comparing the wavelength in the case of purely diffusive and that in the present work. Here, the expressions by Trivedi⁹ are used:

2

$$\lambda = \lambda_{\alpha} + \lambda_{\beta} \tag{4}$$

$$\lambda_{\alpha} = \left(\frac{D_{\beta}}{\nu k_{\alpha}^{*}}\right) \ln \Lambda_{\alpha} \tag{5}$$

$$\Lambda_{\beta} = \left(\frac{D_{\beta}}{\nu k_{\beta}^{*}}\right) \ln \Lambda_{\beta}$$
(6)

$$\Lambda_{\alpha} = \left\{ 1 - \left(\frac{C_{\alpha P}}{C_0} \right) \left[1 - \frac{\Delta T_N^{\alpha}}{C_{LP}(m_l^{\beta} - m_l^{\alpha})} \right] \right\} / \left\{ 1 - \left(\frac{C_{\alpha P}}{C_0} \right) \left[1 + \frac{\Delta T_N^{\beta}}{C_{LP}(m_l^{\beta} - m_l^{\alpha})} \right] \right\}$$
(7)

$$\Lambda_{\beta} = \left\{ 1 - \left(\frac{C_{\beta P}}{C_0}\right) \left[1 + \frac{\Delta T_N^{\beta}}{C_{LP}(m_l^{\beta} - m_l^{\alpha})} \right] \right\} / \left\{ 1 - \left(\frac{C_{\beta P}}{C_0}\right) \left[1 - \frac{\Delta T_N^{\alpha}}{C_{LP}(m_l^{\beta} - m_l^{\alpha})} \right] \right\}$$
(8)

where ΔT_N^{α} and ΔT_N^{β} are the undercoolings required for the heterogeneous nucleation of primary and peritectic phases. m_l^{α} and m_l^{β} are the liquidus slopes of primary α and peritectic β phases, respectively. $C_{\alpha P}$, $C_{\beta P}$ and C_{LP} are the solute concentration of α , β and liquid phase in equilibrium at T_P, k_{α}^* and k_{β}^* are the modified solute redistribution coefficient which has been proposed by Trivedi and Kurz²⁵:

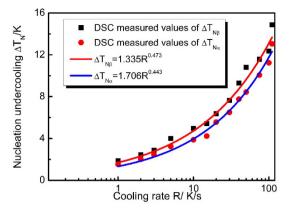


Figure 7. The variation of the measured nucleation undercoolings of both primary Ni_3Sn_2 and peritectic Ni_3Sn_4 phases with cooling rate.

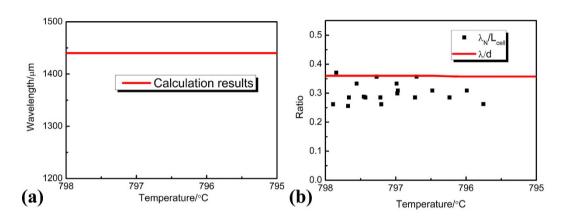


Figure 8. The effect of convection on the morphology of this oscillatory microstructure. (a) the calculation on the wavelength in the purely diffusive condition, (b) the comparison between these two ratios: the ratio of the wavelength of this oscillatory microstructure to the width of the cells λ_N/L_{cell} and the ratio of the wavelength obtained under diffusive condition to the diameter of the sample λ/d .

$$c^* = \frac{C_S - a}{C_L - a} \tag{9}$$

where *a* is the composition at which the linear segments of the solidus and liquidus lines intersect. It can be obtained from Fig. 1 that the values of k_{α}^{*} and k_{α}^{*} are 0.133 and 0.0893, respectively.

Equation (7) and (8) show that the values of the nucleation undercooling are closely associated with band spacing. To describe the influence of thermosolutal convection on wavelength, the extent of convection is characterized by comparing the wavelength obtained in diffusive/convective cases, and the nucleation undercooling of the two phases are needed. Figure 7 shows the measured nucleation undercoolings of both primary and peritectic phases. Statistical regression analysis shows the relations between nucleation undercoolings and cooling rate *R*:

$$\Delta T_N^{\alpha} = 1.335 R^{0.473} \tag{10}$$

$$\Delta T_{N}^{\beta} = 1.\ 706 R^{0.443} \tag{11}$$

The regression coefficient of these two fit are $r^2 = 0.990$, 0.984 respectively. In the present work, the cooling rate *R* is 0.04 K/s. As this cooling rate is too low for the Differential Scanning Calorimetry (DSC) measurement, thus, according to Equation (10) and (11), ΔT_N^{α} and ΔT_N^{β} are 0.291 and 0.410 K. As the nucleation undercooling will not be influenced by convection¹⁰, the above values are used in the following calculation. Through Equations (4–9), the wavelength of this oscillatory microstructure in the case of diffusive condition is obtained. The results in Fig. 8a show the wavelengths predicted by the diffusive model⁹. In order to eliminate the influence of peritectic transformation on wavelength, only the results in the vicinity of T_P is illustrated. It can be found from Fig. 8b that the diffusive predictions in Fig. 8a are much larger than the experimental results. Here λ_N is the wavelength of this oscillatory microstructure, L_{cell} is the width of the cells, λ is the wavelength obtained under diffusive

condition, and *d* is the diameter of the sample. Compared with the diffusive predictions, the change in wavelengths is especially not obvious in the present work, which indicates that the oscillatory thermosolutal convection is weak in the present work. This further confirms the conclusion above that the thermosolutal convection is not heavy in this work, that is, $10 < U_C/v_P < 100$.

But it should be noted that the environment where this oscillatory microstructure evolves is distinct from that of the previous researches^{8-10,12}. The much smaller dimension of this oscillatory microstructure is due to the smaller cell spacing of Sn–36at.% peritectic alloy³⁸. As shown in Equations (10) and (11), the nucleation undercoolings of Ni₃Sn₂/Ni₃Sn₄ phases are really small. In addition, the cell spacing of Ni₃Sn₂ phase is smaller, and the experimental results show that the widths of cells L_{cell} are always smaller than 100 µm in the present work. As a result, it can be concluded that the nucleation rate of Ni₃Sn₂ phase is not slow when the nucleation undercooling required for Ni₃Sn₂ phase is satisfied. Therefore, Thus, the convection filed whose dimension was analogous to the diameter of the sample^{8–10,12} is divided into many local fields which are limited by the cells. Although these local convection fields are interconnected with each other, the oscillatory thermosolutal convection has been limited to local positions to a large extent. This can be confirmed by the results in Fig. 8b. The ratio of the wavelength of this oscillatory microstructure to the width of the cells λ_N/L_{cell} is quite close to the ratio of the wavelength obtained under diffusive condition to the diameter of the sample λ/d . Besides, the small change in λ_N/L_{cell} from about 0.36 to 0.26 confirms the weak oscillatory thermosolutal convection in the present work.

In addition, it can be deduced from Fig. 8b that at temperatures close to T_p where peritectic reaction occurs, the thermosolutal convection is more instable. This is in consistent with what we have discussed in the experiments. Due to the continuous rejection of Sn into the melt at T_p , oscillatory thermosolutal convection is more easily formed. As a result, this oscillatory microstructure can not be observed at the bottom of the cells. This is because that the oscillatory thermosolutal convection in the mushy zone is sensitive to the local morphology of structures. At the bottom of the cells, the permeability is lower than that at the middle of the cells, leading to relatively weaker oscillatory thermosolutal convection at the bottom of the cells. Therefore, this oscillatory microstructure is less likely formed at the bottom of the cells.

As has been discussed above, this oscillatory microstructure is formed due to oscillatory convection. The requirement of oscillatory convection can not be easily satisfied in peritectic systems where both primary and peritectic phases are solid solution phase. During solidification of solid solution phase, a time-independent steady state solute redistribution can be established. Thus, oscillatory convection can not be easily satisfied while the solute redistribution in the liquid at the growing interface can not reach the steady state for intermetallic compound with nil solubility unless the initial composition of the alloy equals to the composition of the intermetallic compound²⁴. For intermetallic compounds with narrow solubility range³⁹, since the initial composition of the alloy can not equal to the composition of the intermetallic compound with narrow solubility range, the melt concentration at the interface decreases following the liquidus line of primary α phase. If the undercooling required for nucleation of the peritectic β phase is satisfied, it is possible to nucleate β phase.

Thus, in this work, as Sn atoms are continuously rejected into the melt during solidification, Sn concentration continues increasing in the melt. This non-steady state solute redistribution is suitable for the formation of oscillatory convection, leading to formation of this oscillatory microstructure. Therefore, the solidification characteristics of peritectic systems containing intermetallic compounds with narrow solubility are distinct from both solid solution phases and intermetallic compounds with nil solubility. Due to their small ranges of solubility, peritectic transformation can take place during peritectic solidification; due to non-steady state solute redistribution of them, oscillatory convection can be more easily satisfied. So, this kind of peritectic systems can not be simply regarded as the intermediate state between those containing solid solution phases and those containing intermetallic compounds with nil solubility range.

Conclusion

An oscillatory microstructure has been observed for the first time during deep-cellular growth of directionally solidified Sn-36at.%Ni alloy where both the primary and peritectic phases are intermetallic compounds with narrow solubility. The initial morphology of this wave-like oscillatory structure is caused by oscillatory convection of the mushy zone during solidification. And its dimension is much smaller as compared with those observed in previous studies, which is associated with smaller cell spacing of this alloy. The influence of convection on this oscillatory microstructure has been characterized through its "wavelength". Due to peritectic transformation, morphology of this oscillatory structure changes during following solidification. It has also been found that, due to the solute redistribution during solidification of intermetallic compounds with narrow solubility range, the oscillatory convection can be more easily formed in this alloy.

Methods

Sn-36at.%Ni peritectic alloy was induction melted under an argon atmosphere from pure Ni and Sn (99.9%). As-cast rods of 3 mm in diameter and 110 mm in length were cut from the ingot. The experiments consisting of melting followed by directional solidification were carried out in a Bridgman-type system consisting of a resistance furnace, a water cooled liquid metal bath filled with liquid Ga–In–Sn alloy, which has been described^{4–8}. Temperature profiles were measured separately using a PtRh30-PtRh6 thermocouple inserted within a fine alumina tube (0.6 mm in inner diameter) down to the center of the samples. During the pulling process, the thermocouple moved downwards with the sample at the same pulling rate. The temperature gradient close to the solid/ liquid interface was deduced from the temperature profiles and was approximately 40 K/mm.

Solidification of Sn-36at.%Ni peritectic alloy was carried out at growth rate of 1 μ m/s in a constant temperature gradient (40 K/mm). With a predetermined growth distance of 30 mm reached, the samples were quenched into liquid Ga-In-Sn alloy quickly to preserve the microstructure. Then, the samples were longitudinally sectioned, polished and etched with a solution of 10g FeCl₃-20 ml HCl-180 ml H₂O for further analysis.

The microstructures of the longitudinal section of rods was analyzed by scanning electron microscopy (SEM (Quanta-200)). Energy dispersive X-ray spectrometer (EDS) was applied to determine composition of phases.

The measurement on the nucleation undercooling of both primary Ni₃Sn₂ and peritectic Ni₃Sn₄ phases were performed by differential scanning clorimetry (DSC-SETARAM) in a continuous mode. The calorimeter was calibrated by measuring the melting temperatures (T_M) of metallic In, Sn, Al, Au and Pd (99.999 mass % purity). T_M was obtained with an accuracy of $T_M \pm 0.5$ °C for all cases. As-cast rods of 8 mm in diameter and length of 10 mm were put into a high-purity alumina crucible of 20 mm length and 10 mm inner diameter. After heating to 1,250 °C at a rate of 10 °C/min, the sample was held for 30 min at this temperature, then the samples were cooled to room temperatureat a range of cooling rates $1 \sim 100$ °C/s. All the experiments were carried out in Ar atmosphere.

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Author Contributions

P.P., X.Z., J.G., Y.Q. and J. J. designed the project. P.P. and X.Z. conducted the directional solidification. P.P., X.Z. and J.G. prepared the specimen. P.P. carried out the optical microscope observation. P.P. analyzing the data and presenting the results. P.P. wrote the paper. All authors contributed to discussions of the results.

Additional Information

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